



Docket: 14467.05

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

First Named Inventor:	John P. Snyder	
Appln. No.:	10/796,514	
Filing Date:	March 9, 2004	Examiner: Kim, Su C.
Title:	Transistor Having High Dielectric Constant Gate Insulating Layer and Source and Drain Forming Schottky Contact with Substrate	Group Art Unit: 2823

PETITION FOR EXTENSION OF PERIOD FOR RESPONSE

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

I hereby certify that this document is being sent via First Class U.S. mail addressed to: Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 21st day of November, 2005.

Sue Xu
(Signature)

Dear Sir:

Pursuant to 37 C.F.R. § 1.136(a), Applicant hereby petitions for an extension of three (3) months from August 20, 2005 to November 20, 2005 within which to respond to the office action dated May 20, 2005. A check in the amount of \$510.00 is enclosed herewith to cover the extension fee.

The Commissioner is hereby authorized to charge any deficiencies or credit any overpayments to Deposit Account No. 04-1420.

11/25/2005 FMETEK1 00000053 10796514

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510.00 OP

Respectfully submitted,

DORSEY & WHITNEY LLP
Customer Number 25763

Date: Nov. 21, 2005

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